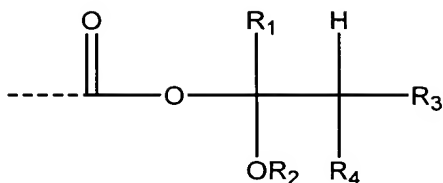


CLAIMS

What is claimed is:

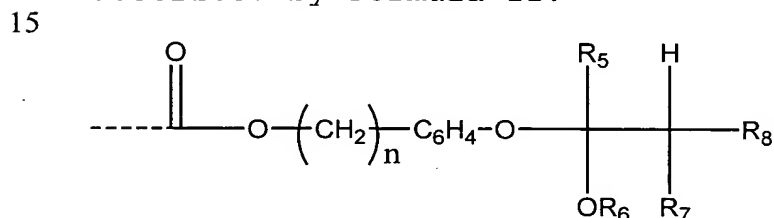
1. A positive imageable, particulate-filled photoresist composition comprising (a) at least one
5 positive imageable photopolymer system, and (b) about 1 to about 70 vol% particulates.
2. The composition of Claim 1 wherein the particulates are selected from the group consisting of glass, oxides, carbides, nitrides, metals, metal
10 alloys, metalloids, metalloid alloys, metal/metalloid alloys, carbon and mixtures thereof.
3. The composition of Claim 2 wherein the oxides are selected from the group consisting of aluminum oxides, silicon oxides, tin oxides and mixtures
15 thereof.
4. The composition of Claim 1 wherein the particulates are selected from the group consisting of transition metals and their alloys.
5. The composition of Claim 4 wherein the
20 transition metals are selected from the group consisting of Al, Cu, Ag, Au, Pt, and Pd.
6. The composition of Claim 1 wherein the particulates are selected from the group consisting of zinc, thallium, germanium, cadmium, indium, tin,
25 antimony, lead, bismuth, and their alloys.
7. The composition of Claim 1 wherein the particulates are selected from the group consisting of metal/metalloid alloys.
8. The composition of Claim 2 wherein the carbon
30 is in the form of carbon nanotubes.
9. The composition of Claim 1 wherein the photopolymer system is selected from the group consisting of novolac-diazonaphthoquinone resins.
10. The composition of Claim 1 wherein the
35 photopolymer system is selected from the group of resins consisting of (meth)acrylate polymers and copolymers, wherein the resins contain pendant groups described by Formula I:



Formula I

5 wherein R_1 is hydrogen or C_1 - C_6 alkyl; R_2 is C_1 - C_6 alkyl; and R_3 and R_4 independently are hydrogen or C_1 - C_6 alkyl; and wherein R_1 and R_2 , or R_1 and R_3 , or R_2 and R_3 may be joined to form a 5-, 6-, or 7-membered ring.

10 11. The composition of Claim 1 wherein the photopolymer system is selected from the group of resins consisting of (meth)acrylate polymers and copolymers, wherein the resins contain pendant groups described by Formula II:

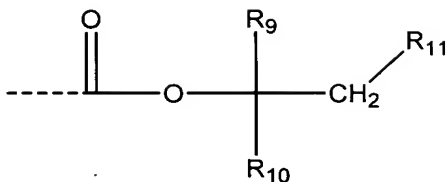


Formula II

20 wherein n is 0-4; R_5 is hydrogen or C_1 - C_6 alkyl; R_6 is C_1 - C_6 alkyl; and R_7 and R_8 independently are hydrogen or C_1 - C_6 alkyl; and wherein R_5 and R_6 , or R_5 and R_7 , or R_6 and R_7 may be joined to form a 5-, 6-, or 7-membered ring.

25 12. The composition of Claim 1 wherein the photopolymer system is selected from the group of resins consisting of (meth)acrylate polymers and copolymers, wherein the resins contain pendant groups described by Formula III:

30



Formula III

wherein R₉ is hydrogen or lower alkyl; R₁₀ is lower
 5 alkyl; and R₁₁ is hydrogen or lower alkyl; and wherein
 a lower alkyl group includes alkyl groups having 1 to 6
 linear or 3 to 6 cyclic carbon atoms.

13. The composition of Claim 1, wherein the
 photopolymer system comprises acid labile monomeric
 10 components selected from:
- tetrahydropyranyl methacrylate (or acrylate);
 - tetrahydropyranyl p-vinylbenzoate;
 - 1-ethoxy-1-propyl p-vinylbenzoate;
 - 4-(2-tetrahydropyranyloxy)benzyl methacrylate
 15 (or acrylate);
 - 4-(1-butoxyethoxy)benzyl methacrylate (or
 acrylate);
 - t-butyl methacrylate (or acrylate);
 - neopentyl methacrylate (or acrylate);
 - 20 1-bicyclo{2,2,2}octyl methacrylate (or
 acrylate) and their derivatives;
 - 1-bicyclo{2,2,1}heptyl methacrylate (or
 acrylate) and their derivatives;
 - 1-bicyclo{2,1,1}hexyl methacrylate (or
 25 acrylate) and their derivatives;
 - 1-bicyclo{1,1,1}pentyl methacrylate (or
 acrylate) and their derivatives; and
 - 1-adamantyl methacrylate (or acrylate) and
 their derivatives.

- 30 14. The composition of Claim 1 further comprising
 additives selected from the group consisting of
 solvents and viscosity aids.

15. The composition of Claim 1 wherein the particulates comprise about 20 to about 70 vol% of the composition.

16. The composition of Claim 1 wherein the
5 particulates are less than 100 microns in their longest dimension.

17. The composition of Claim 1 wherein the particulates are less than 10 microns in their longest dimension.

10 18. The composition of Claim 1 in the form of a printable paste.

19. The composition of Claim 1 in the form of a film.

15 20. An electron field emitting film comprising the composition of Claim 1.

21. A field emission triode comprising the film of Claim 20.

22. A field emission display comprising the film of Claim 20.

20 23. A lighting device comprising the film of Claim 20.

24. A vacuum electronic device comprising the film of Claim 20.

25 25. A process for creating images on a substrate comprising:

- (a) depositing the composition of Claim 1 as a film on a substrate;
- (b) exposing the film imagewise to radiation to form exposed and unexposed portions thereof; and
- (c) removing the exposed portions to form a developed image.

26. The process of Claim 25 further comprising heating the developed image to form a first patterned
35 structure.

27. The process of Claim 26 wherein forming a patterned structure comprises forming an insulator.

28. The process of Claim 26 wherein forming a patterned structure comprises forming a conductor.

29. The process of Claim 26 wherein forming a patterned structure comprises forming a semi-conductor.

5 30. The process of Claim 25 wherein the deposited film is a thick film.

31. A process according to Claim 26 further comprising depositing a composition of Claim 1, as a second film, onto the first patterned structure.

10 32. The process of Claim 31 further comprising:

(a) exposing the second film imagewise to radiation to form exposed and unexposed portions thereof; and

15 (b) removing the exposed portions to form a second developed image; and

(c) heating the second developed image to form a second patterned structure;

wherein the first and second patterned structures have the same size and shape.

20 33. A process for creating a multi-layer patterned structure comprising:

(a) depositing a first composition of Claim 1 as a first film on a substrate;

25 (b) depositing a second composition of Claim 1, as a second film, onto the first film;

(c) exposing the first and second films imagewise to radiation to form exposed and unexposed portions;

30 (d) removing the exposed portions to form a developed image.

34. The process of Claim 33 further comprising heating the developed image to form a patterned structure.

35 35. The process of Claim 34 wherein forming a patterned structure comprises forming an insulator.

36. The process of Claim 34 wherein forming a patterned structure comprises forming a conductor.

37. The process of Claim 34 wherein forming a patterned structure comprises forming a semi-conductor.

38. The process of Claim 33 wherein the deposited film is a thick film.

5 39. A process according to Claim 34 further comprising depositing a third composition of Claim 1, as a third film, onto the patterned structure.

40. A process according to Claim 25 or 33 wherein the deposition comprises screen printing, spin coating,
10 ink jet printing, contact printing or stenciling.